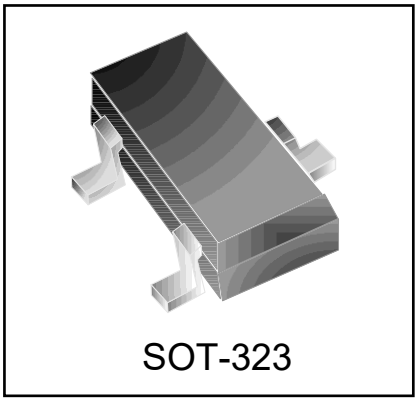
WM03N20G

N-Channel Enhancement MOSFET

Features

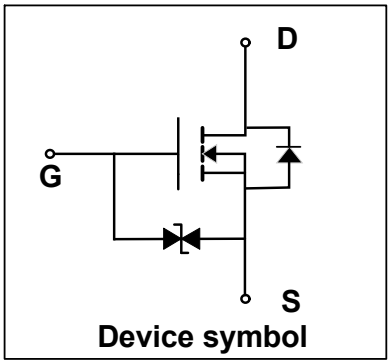
- Way-on Small Signal MOSFETs
- V_{DS}= 30V, I_D = 1.5A
  Typ. $R_{DS(on)}$ = 107mΩ @ V_{GS} = 10V
  Typ. $R_{DS(on)}$ = 117mΩ @ V_{GS} = 4.5V
- Trench LV MOSFET Technology
- ESD Protected



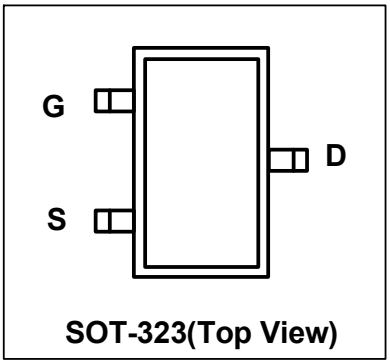
Mechanical Characteristics

- SOT-323 Package
- Marking: Making Code
- RoHS Compliant & Halogen-Free

Schematic & PIN Configuration



Device symbol



SOT-323(Top View)

Absolute Maximum Rating (T_A=25°C unless otherwise noted)

Parameter		Symbol	Value	Unit
Drain-Source Voltage		V_{DS}	30	V
Gate-Source Voltage		V_{GS}	±12	V
Continuous Drain Current	T_A=25°C	I_D	1.5	A
	T_A=100°C		0.92	
Pulsed Drain Current[1]		I_{DM}	6	A
Power Dissipation	T_A=25°C	P_D	0.6	W
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55 to 150	°C

Thermal Characteristics

Parameter	Symbol	Value	Unit
Thermal Resistance from Junction to Ambient[2]	$R_{\theta JA}$	208	°C/W

Electrical Characteristics (T_J=25°C unless otherwise noted)

Parameter		Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics							
Drain-Source Breakdown Voltage		$V_{(BR)DSS}$	V_{GS} = 0V, I_D = 250μA	30	-	-	V
Gate-Body Leakage Current		I_{GSS}	V_{DS} = 0V, V_{GS} = ±12V	-	-	±10	μA
Zero Gate Voltage Drain Current	T_J=25°C	I_{DSS}	V_{DS} = 30V, V_{GS} = 0V	-	-	1	μA
	T_J=100°C			-	-	100	
Gate Threshold Voltage		$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250μA	0.5	1	1.5	V
Drain-Source on-State Resistance[3]		$R_{DS(on)}$	V_{GS} = 10V, I_D = 1.5A	-	107	130	mΩ
			V_{GS} = 4.5V, I_D = 1A	-	117	145	
			V_{GS} = 2.5V, I_D = 0.5A	-	150	190	
Dynamic Characteristics[4]							
Input Capacitance		C_{iss}	V_{GS} = 0V, V_{DS} = 15V, f = 1MHz	-	115	-	pF
Output Capacitance		C_{oss}		-	14	-	
Reverse Transfer Capacitance		C_{rss}		-	8.5	-	
Switching Characteristics[4]							
Total Gate Charge		Q_g	V_{GS} = 10V, V_{DS} = 15V, I_D = 1.5A	-	3.1	-	nC
Gate-Source Charge		Q_{gs}		-	0.5	-	
Gate-Drain Charge		Q_{gd}		-	0.2	-	
Turn-on Delay Time		$t_{d(on)}$	V_{GS} = 10V, V_{DD} = 15V, R_G = 3Ω, I_D = 1.5A	-	1.3	-	ns
Turn-on Rise Time		t_r			3.5	-	
Turn-off Delay Time		$t_{d(off)}$		-	6	-	
Turn- off Fall Time		t_f		-	2.4	-	
Drain-Source Body Diode Characteristics							
Body Diode Voltage[3]		V_{SD}	I_S= 1A, V_{GS}= 0V	-	-	1.2	V
Continuous Source Current		I_S	-	-	-	1.5	A

Notes:

1. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$=150°C.

2. The data tested by surface mounted on a 1 inch2 FR-4 board with 2OZ copper, The value in any given application depends on the user's specific board design.

3. Pulse Test: Pulse width≤300μs, duty cycle≤2%.

4. This value is guaranteed by design hence it is not included in the production test.

Typical Characteristics

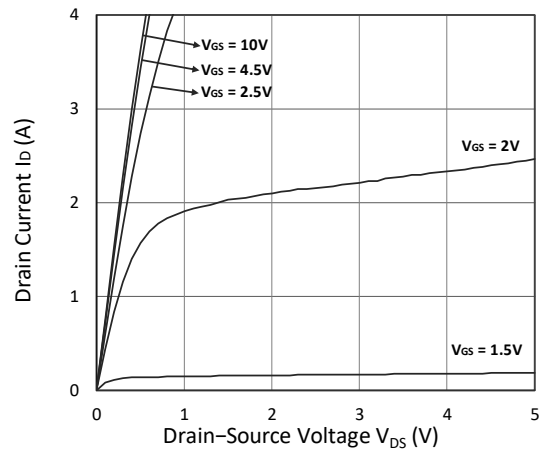


Figure 1. Output Characteristics

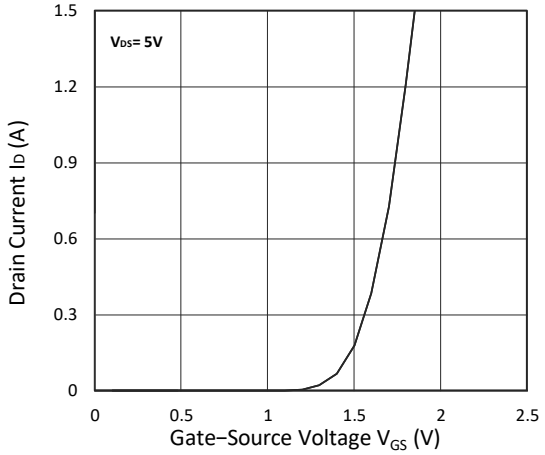


Figure 2. Transfer Characteristics

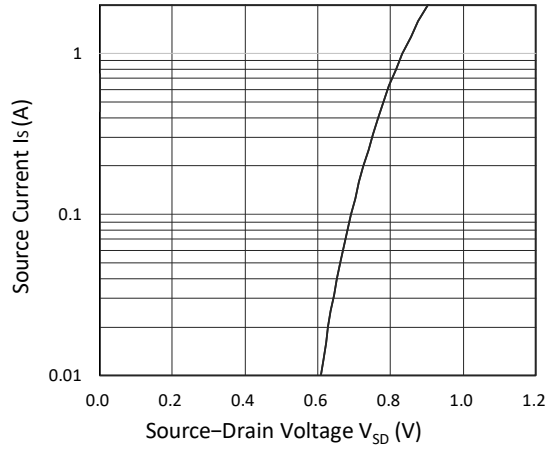


Figure 3. Forward Characteristics of Reverse

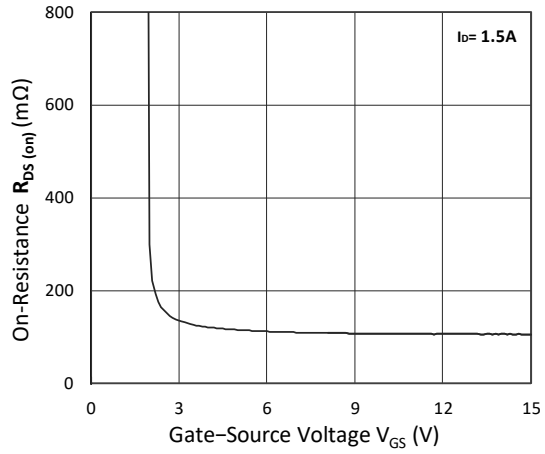


Figure 4. $R_{DS(on)}$ vs. V_{GS}

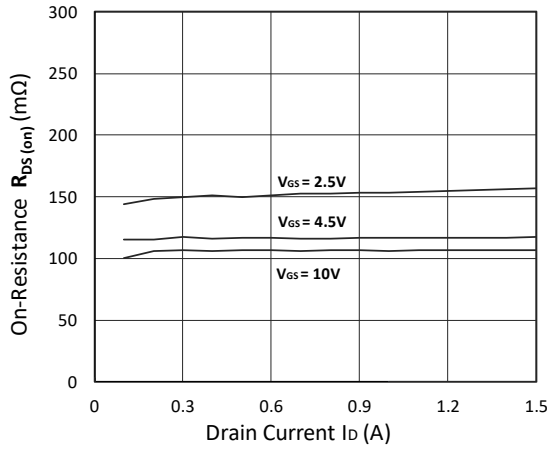


Figure 5. $R_{DS(on)}$ vs. I_D

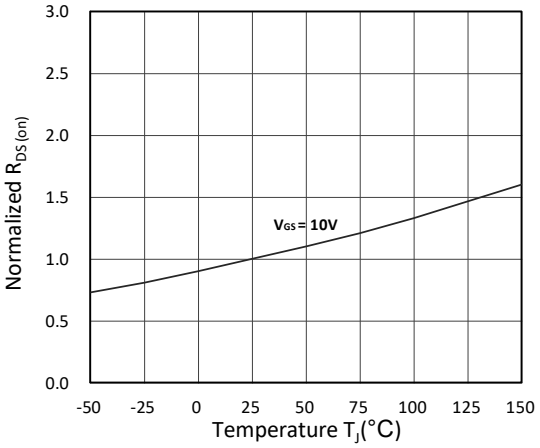


Figure 6. Normalized $R_{DS(on)}$ vs. Temperature

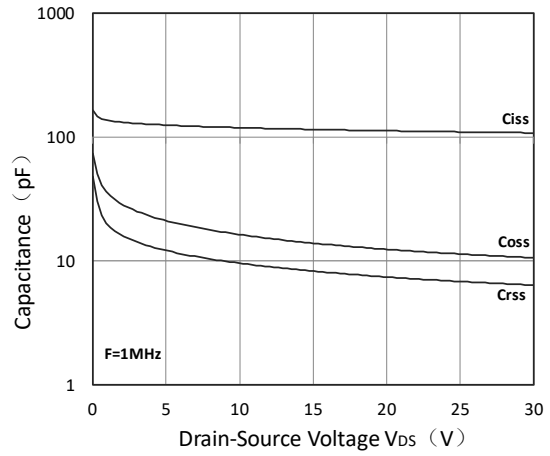


Figure 7. Capacitance Characteristics

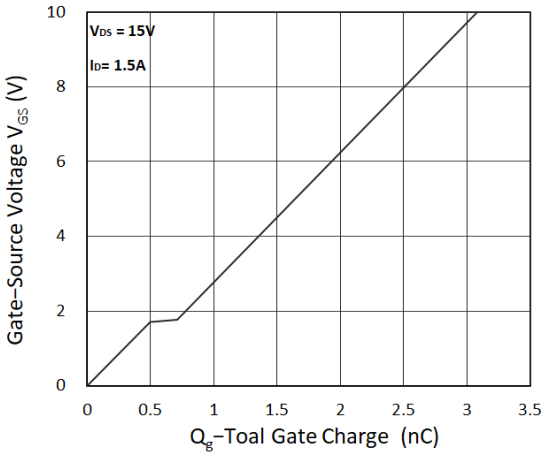
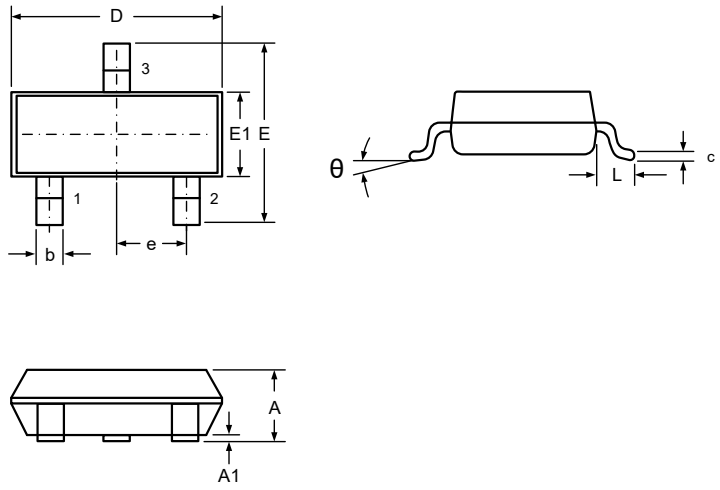
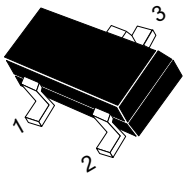


Figure 8. Gate Charge Characteristics

Outline Drawing – SOT-323

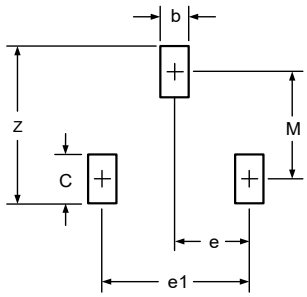
PACKAGE OUTLINE





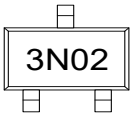
SOT-323

DIMENSIONS				
SYMBOL	MILLIMETER		INCHES	
	MIN	MAX	MIN	MAX
A	0.90	1.10	0.035	0.043
A1	0.00	0.10	0.000	0.004
D	2.00	2.20	0.079	0.087
b	0.20	0.40	0.008	0.016
c	0.08	0.15	0.003	0.006
E	2.15	2.45	0.085	0.096
E1	1.15	1.35	0.045	0.053
e	0.65TYP		0.026TYP	
L	0.525 REF		0.021 REF	
θ	0	8°	0	8°



DIMENSIONS		
DIM	INCHES	MILLIMETERS
M	0.076	1.90
C	0.036	0.9
Z	0.110	2.8
e	0.026	0.65
e1	0.052	1.30
b	0.028	0.7

Marking Codes

Part Number	WM03N20G
Marking Code	

Package Information

Qty：3k/Reel

CONTACT INFORMATION

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For additional information, please contact your local Sales Representative.

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Product Specification Statement

1. The product specification aims to provide users with a reference regarding various product parameters, performance, and usage. It presents certain aspects of the product's performance in graphical form and is intended solely for users to select product and make product comparisons, enabling users to better understand and evaluate the characteristics and advantages of the product. It does not constitute any commitment, warranty, or guarantee.

2. The product parameters described in the product specification are numerical values, characteristics, and functions obtained through actual testing or theoretical calculations of the product in an independent or ideal state. Due to the complexity of product applications and variations in test conditions and equipment, there may be slight fluctuations in parameter test values. WAYON shall not guarantee that the actual performance of the product when installed in the customer's system or equipment will be entirely consistent with the product specification, especially concerning dynamic parameters. It is recommended that users consult with professionals for product selection and system design. Users should also thoroughly validate and assess whether the actual parameters and performance when installed in their respective systems or equipment meet their requirements or expectations. Additionally, users should exercise caution in verifying product compatibility issues, and WAYON assumes no responsibility for the application of the product.

3. WAYON strives to provide accurate and up-to-date information to the best of our ability. However, due to technical, human, or other reasons, WAYON cannot guarantee that the information provided in the product specification is entirely accurate and error-free. WAYON shall not be held responsible for any losses or damages resulting from the use or reliance on any information in these product specifications. WAYON reserves the right to revise or update the product specification and the products at any time without prior notice, and the user's continued use of the product specification is considered an acceptance of these revisions and updates. Prior to purchasing and using the product, users should verify the above information with WAYON to ensure that the product specification is the most current, effective, and complete. If users are particularly concerned about product parameters, please consult WAYON in detail or request relevant product test reports. Any data not explicitly mentioned in the product specification shall be subject to separate agreement.

4. Users are advised to pay attention to the parameter limit values specified in the product specification and maintain a certain margin in design or application to ensure that the product does not exceed the parameter limit values defined in the product specification. This precaution should be taken to avoid exceeding one or more of the limit values, which may result in permanent irreversible damage to the product, ultimately affecting the quality and reliability of the system or equipment.

5. The design of the product is intended to meet civilian needs and is not guaranteed for use in harsh environments or precision equipment. It is not recommended for use in systems or equipment such as medical devices, aircraft, nuclear power, and similar systems, where failures in these systems or equipment could reasonably be expected to result in personal injury. WAYON shall assume no responsibility for any consequences resulting from such usage.

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